



Micro Commercial Components 20736 Marilla Street Chatsworth

CA 91311

Phone: (818) 701-4933 Fax: (818) 701-4939 **SI2301** 

### **Features**

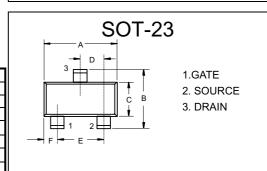
- -20V,-2.8A,  $R_{DS(ON)}$ =120m  $\Omega$  @ $V_{GS}$ =-4.5V  $R_{DS(ON)}$ =150m  $\Omega$  @V<sub>GS</sub>=-2.5V
- High dense cell design for extremely low R<sub>DS(ON)</sub>
- Rugged and reliable
- High Speed Switching
- SOT-23 Package
- Marking Code: S1 Epoxy meets UL 94 V-0 flammability rating

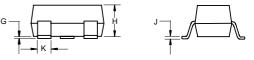
Moisture Sensitivity Level 1

Maximum Ratings @ 25°C Unless Otherwise Specified

Symbol	Parameter	Rating	Unit	
$V_{DS}$	Drain-source Voltage	-20	V	
I <sub>D</sub>	Drain Current-Continuous	-2.8	Α	
I <sub>DM</sub>	Drain Current-Pulsed <sup>a</sup>	-10	Α	
$V_{GS}$	Gate-source Voltage	±8	V	
$P_{D}$	Total Power Dissipation	1.25	W	
R⊕JA	Thermal Resistance Junction to Ambient <sup>b</sup>	100	°C/W	
TJ	Operating Junction Temperature	-55 to +150	$^{\circ}\mathbb{C}$	
T <sub>STG</sub>	Storage Temperature	-55 to +150	$^{\circ}\mathbb{C}$	

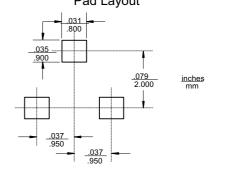
### **P-Channel Enhancement Mode Field Effect Transistor**



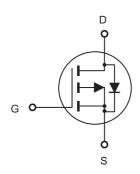


DIMENSIONS					
	INCHES		MM		
DIM	MIN	MAX	MIN	MAX	NOTE
Α	.110	.120	2.80	3.04	
В	.083	.104	2.10	2.64	
С	.047	.055	1.20	1.40	
D	.035	.041	.89	1.03	
Е	.070	.081	1.78	2.05	
F	.018	.024	.45	.60	
G	.0005	.0039	.013	.100	
Н	.035	.044	.89	1.12	
J	.003	.007	.085	.180	
K	.015	.020	.37	.51	

# Suggested Solder Pad Layout



### **Internal Block Diagram**





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### **Electrical Characteristics** T<sub>A</sub> = 25°C unless otherwise noted

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS} = 0V, I_{D} = -250\mu A$	-20			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V			-1	μA
Gate Body Leakage Current, Forward	I <sub>GSSF</sub>	$V_{GS} = 8V, V_{DS} = 0V$			100	nA
Gate Body Leakage Current, Reverse	Igssr	$V_{GS}$ = -8V, $V_{DS}$ = 0V			-100	nA
On Characteristics <sup>c</sup>						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{GS} = V_{DS}, I_{D} = -250 \mu A$	-0.45			V
Static Drain-Source		$V_{GS} = -4.5V, I_{D} = -2.8A$		80	120	mΩ
On-Resistance	R <sub>DS(on)</sub>	$V_{GS} = -2.5V, I_{D} = -2.0A$		110	150	mΩ
Forward Transconductance	9 <sub>FS</sub>	$V_{DS} = -5V, I_{D} = -2.8A$		8		S
Dynamic Characteristics d					•	
Input Capacitance	C <sub>iss</sub>	\/ O\/ \/ O\/		880		pF
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -6V, V_{GS} = 0V,$ f = 1.0 MHz		270		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	1		175		pF
Switching Characteristics d						
Turn-On Delay Time	t <sub>d(on)</sub>			11	20	ns
Turn-On Rise Time	t <sub>r</sub>	$V_{DD} = -6V, I_{D} = -1A,$ $V_{GS} = -4.5V, R_{GEN} = 6\Omega$		5	10	ns
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> = -4.5V, K <sub>GEN</sub> = 052		32	65	ns
Turn-Off Fall Time	t <sub>f</sub>			23	45	ns
Total Gate Charge	$Q_g$	\/ - C\/   - 0 0 A		11	14.5	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = -6V, I_{D} = -2.8A,$ $V_{GS} = -4.5V$		1.5		nC
Gate-Drain Charge	Q <sub>gd</sub>	- 63		2.1		nC
Drain-Source Diode Characteristics and Maximun Ratings						
Drain-Source Diode Forward Current b	Is				-0.75	Α
Drain-Source Diode Forward Voltage °	V <sub>SD</sub>	$V_{GS} = 0V, I_{S} = -0.75A$			-1.2	V

Notes:
a.Repetitive Rating: Pulse width limited by maximum junction temperature.b.Surface Mounted on FR4 Board, t < 5 sec.
c.Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
d.Guaranteed by design, not subject to production testing.



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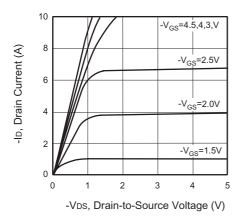
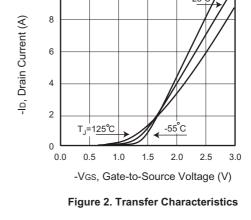


Figure 1. Output Characteristics



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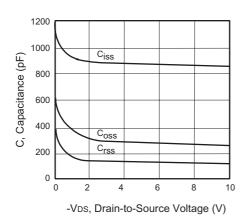


Figure 3. Capacitance

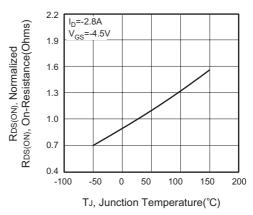


Figure 4. On-Resistance Variation with Temperature

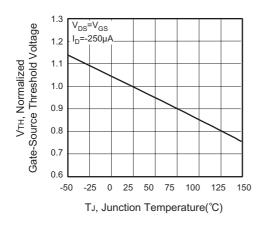


Figure 5. Gate Threshold Variation with Temperature

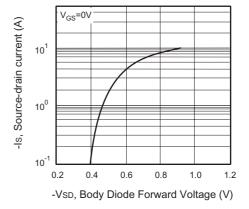


Figure 6. Body Diode Forward Voltage Variation with Source Current



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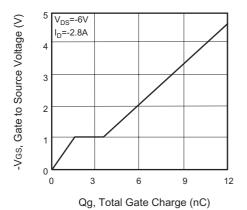


Figure 7. Gate Charge

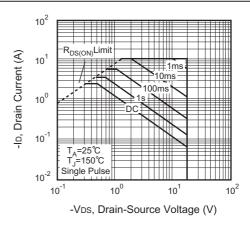


Figure 8. Maximum Safe Operating Area

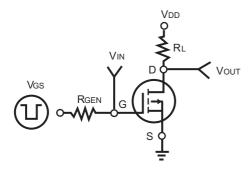


Figure 9. Switching Test Circuit

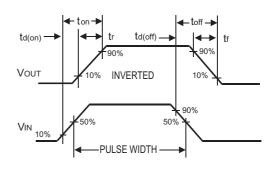


Figure 10. Switching Waveforms

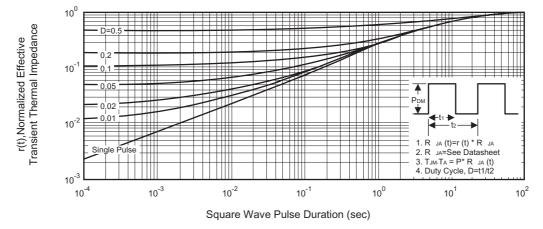


Figure 11. Normalized Thermal Transient Impedance Curve



### Ordering Information:

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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